

Développements de pixels CMOS à l'IPHC : détection alpha, beta, ions & X-rays

Journées thématiques du Réseau Semi-conducteurs - Les détecteurs à pixels
Grenoble, 31 mai – 1^{er} juin 2018

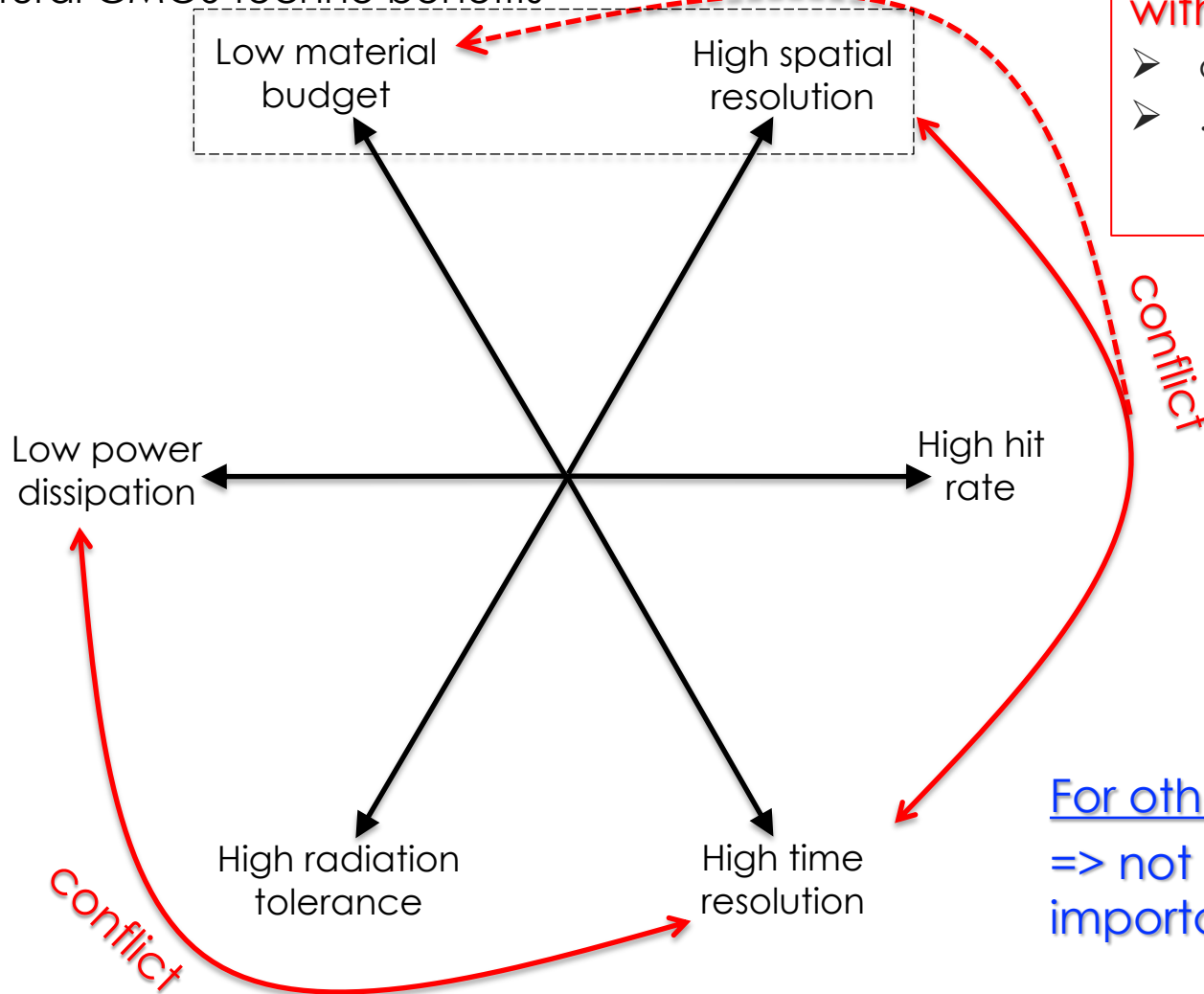
- Depleted CMOS pixel sensors
- Application to X-rays
- Application to charged particles

J. Baudot



Requirements from tracking/vertexing

Natural CMOS techno benefits



Parameters correlated within one technology

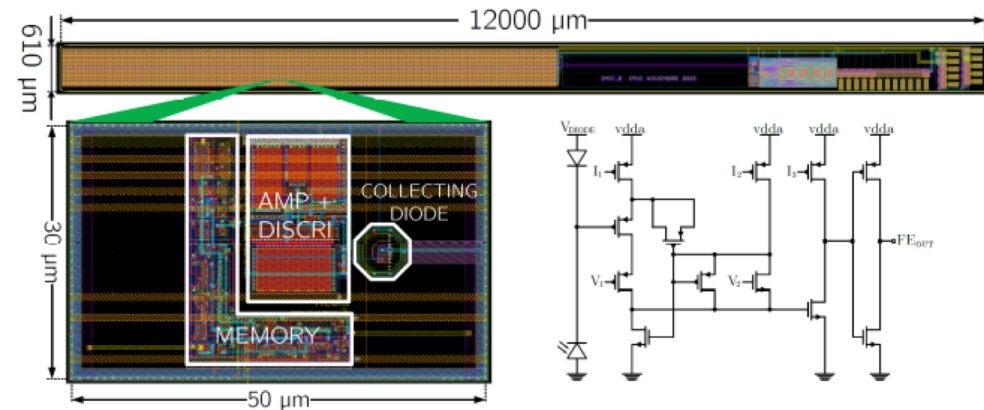
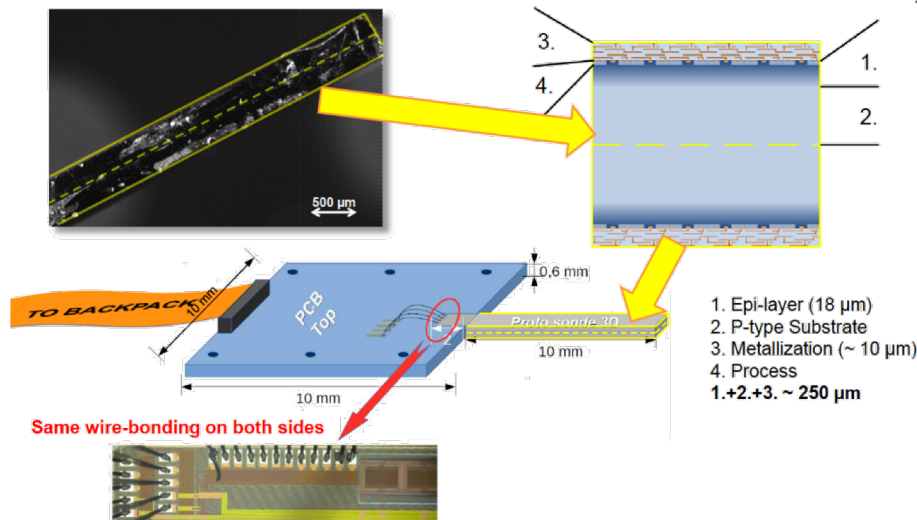
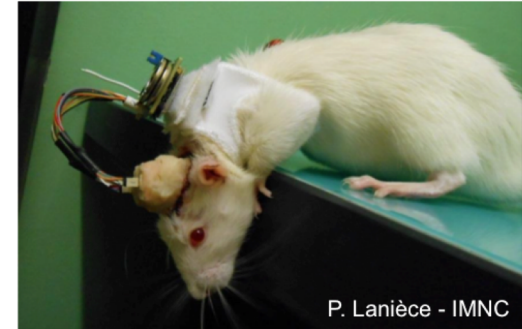
- optimisation required...
- ...or going to 3D

For other applications
=> not all requirements important

Charged particles dosimetry

■ Molecular imaging with β^+ emitters in moving rodent

- MAPSSIC: extreme integration in specific environment
 - Constraint on size and power dissipation
 - **IMNC, IPHC, CPPM, CERMEP, NeuroPSi**
- Exploit CMOS sensors derived from ALICE
 - One active probe = 160 μ W
 - For few counts / s
- Wireless connection from μ Controller



probe in the brain :

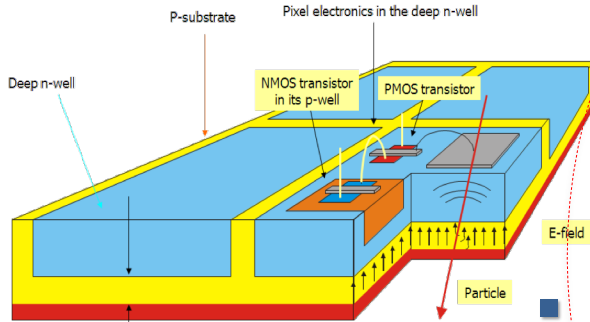
- section $\sim 500 \times 500 \mu\text{m}^2$
- sensitive volume (18 μm) immune to γ
- first prototypes under test

Three ways to deplete MAPS

Depletion depth $\propto (V_{\text{bias}} \times \rho)^\alpha$ with $\alpha \lesssim 1/2$

High Voltage

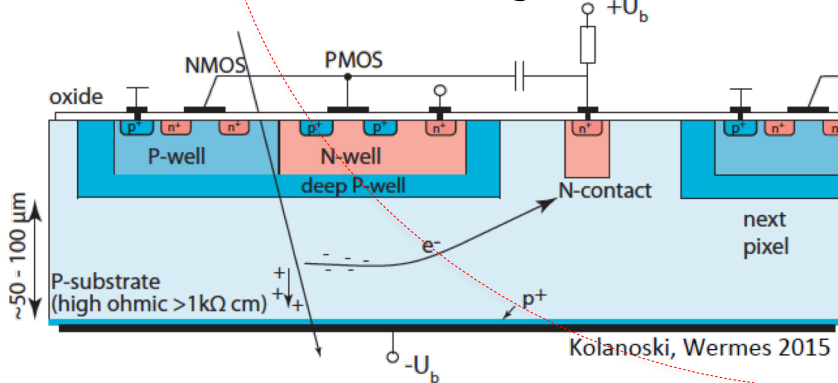
- Large diode



I.Pieric 2010

High Resistivity

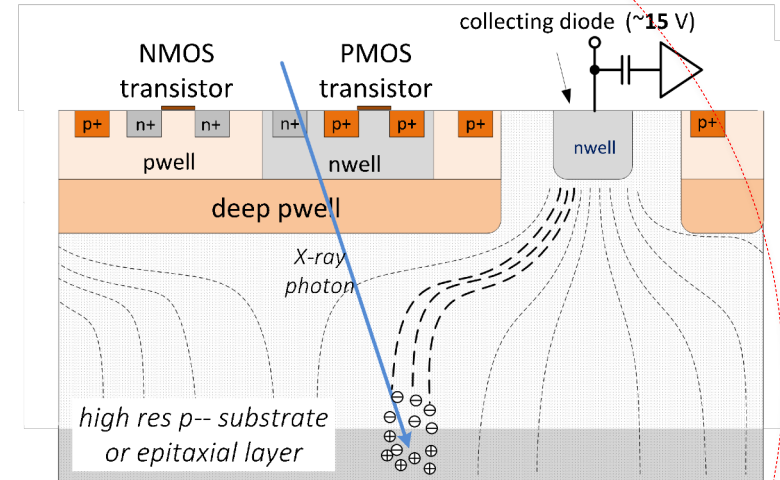
- Back biasing
- Small/Large diode



Kolanoski, Wermes 2015

High Resistivity

- Top biasing
- Small diode



M.Kachel 2013

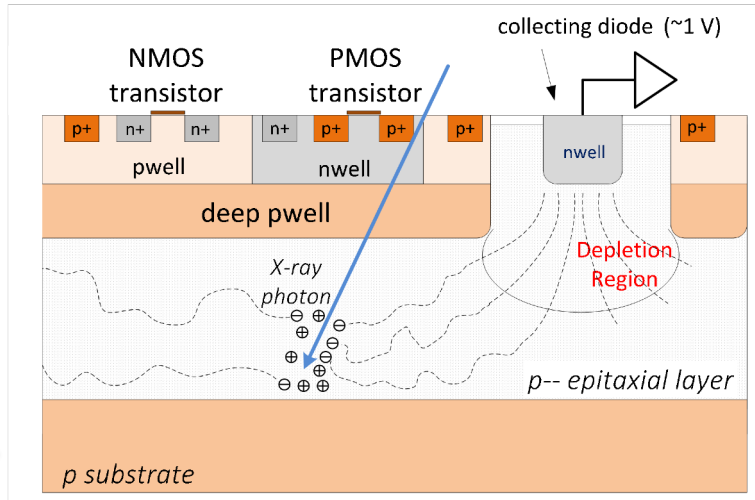
Target small pixels

! All with multiple wells CMOS process

Studied at IPHC

Front-depletion with small diode

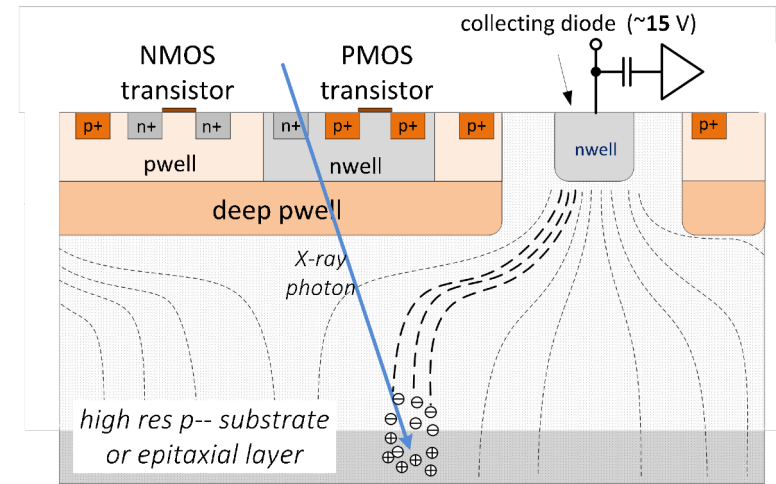
Low-resistivity layer
(the std old way)



Charges move MOSTLY from therm. diffusion

- Long (~100 ns) collection time
- Important charge sharing

Depleted MAPS
(the new way)



Charges move MOSTLY from E drift

- Short (< 10 ns) collection time
- Low charge sharing

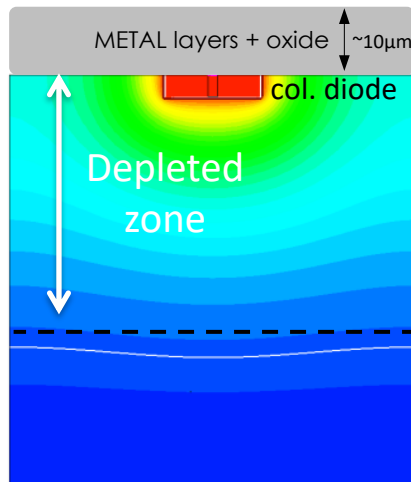
Back-side illumination

- Substrate removed (50 μm easy in industry)
- Sensors too thin (~20 μm) => front support
- Complex connexion (costly)
- Could stay thick => no complexity

Back Side Processing

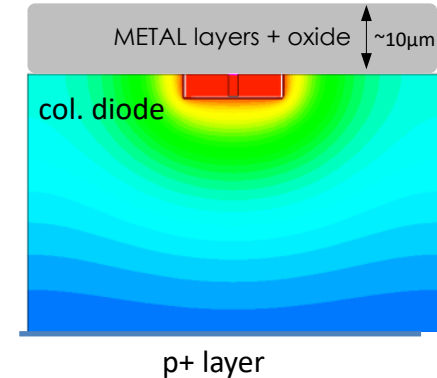
■ Goal: « costless » BSI sensor

Based on CZ wafer
with resistivity $\gg 600 \Omega \cdot \text{cm}$



[J. HEYMES]

- >
- **Thinning 50 μm**
 - **Ion implant**
 - **Annealing**

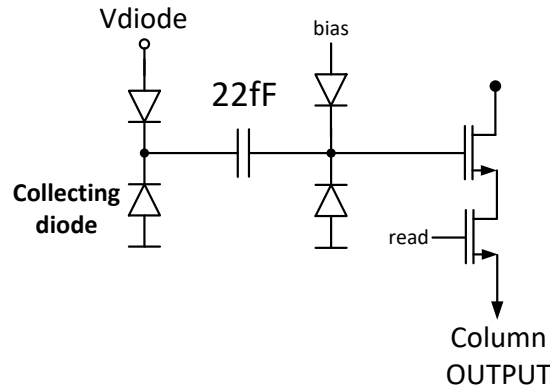


Major benefit expected

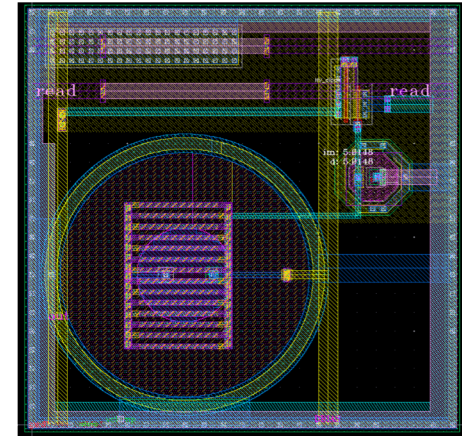
- Sensitivity to low penetrating radiations
- X-rays $\lesssim 1 \text{ keV}$
- Alpha or slow ions
- Visible photon (needs extra coating)

Depletion on prototype sensors

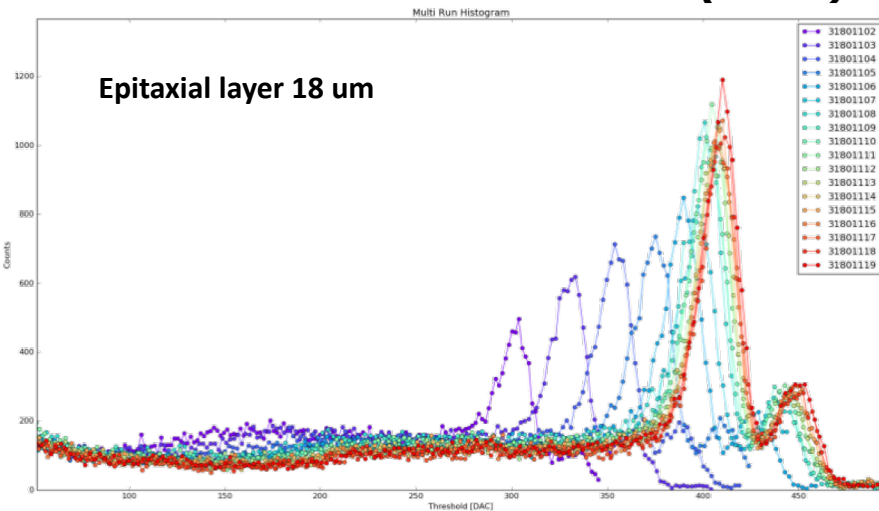
PIPPER-1 (2014), PIPPER-2 (2016), PIPPER-3 (2017)



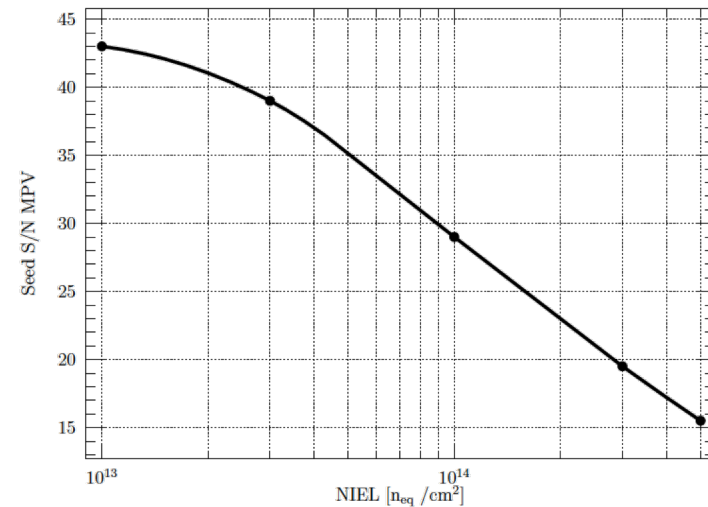
- Prototype chip 32 x 128 pixels
- Analog outputs
- Pixel size 22x22 μm
- **AC coupled collecting diode**
- Produced on two substrates:
 - Epitaxial layer 18 μm
 - Czochralski substrate + PULSION post-process



⁵⁵Fe irrad. function of diode bias (1-19V)



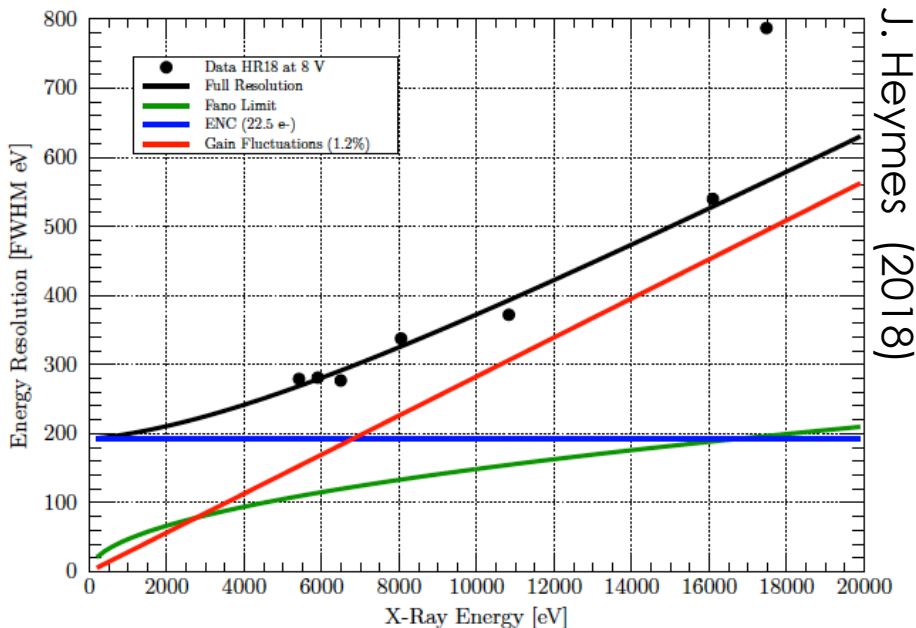
β -source SNR at -20 C, after neutron irradiation



Some PIPPER performances

■ Energy resolution

- Temperature ~ 10 °C
- Computed after clustering

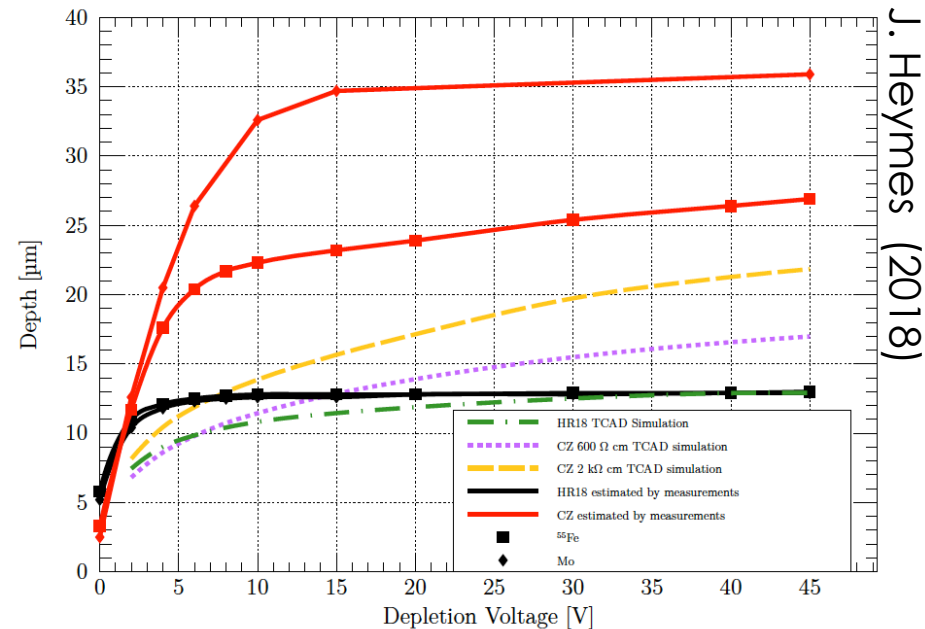


J. Heymes (2018)

- dominated by pixel-gain & charge-collection fluctuations
- Linearity checked up to 15 keV

■ Collection depth

- Computed from counts in peaks
- Deeper collection exists but at lower energy resolution

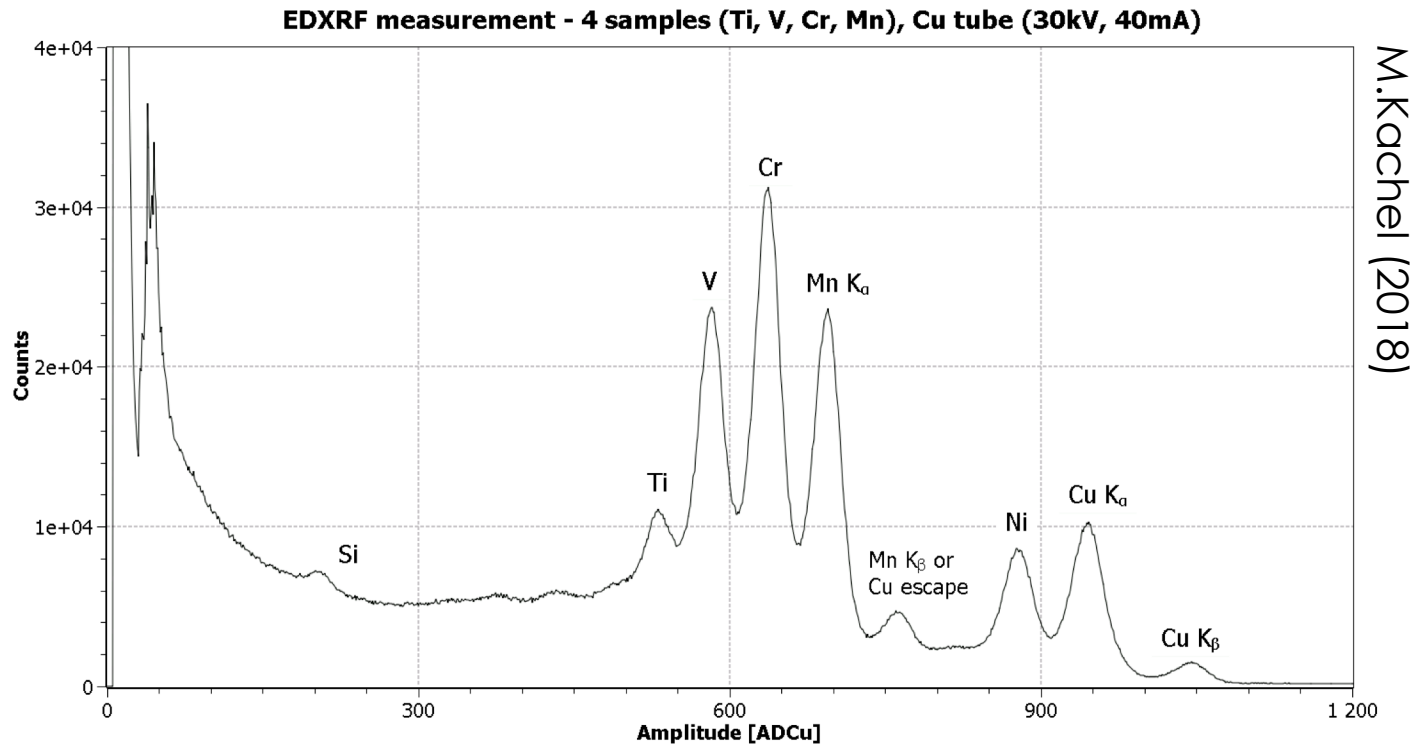


J. Heymes (2018)

- 40 μm not really fully depleted BUT fully collect

■ Irradiation of Ti, V, Cr, Mn samples

- X-ray lamp with Cu target
- Ni-shielded
- Note/ Si-line = internal Fluorescence



Prototype small pixel X-ray counter

Counting Low energy X-ray - Mimosa 22SX

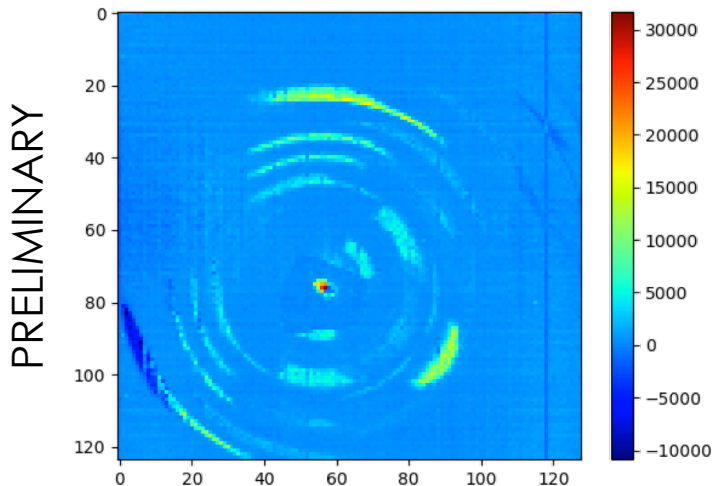


Requirements:

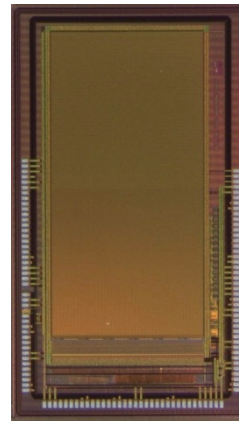
- X-Ray Energy Range [few 100 eV – 5 keV] with 100% QE
- Counting Dynamic [1-10⁷] ph/pix/s
- High Spatial Resolution (pixel pitch ~ 20 μm)

Test at HERMES beam-line

- F.Orsini *et al.*
- Simple pin-hole diffraction
- Low energy, down to 1 keV

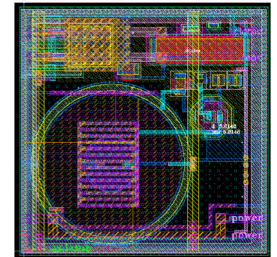
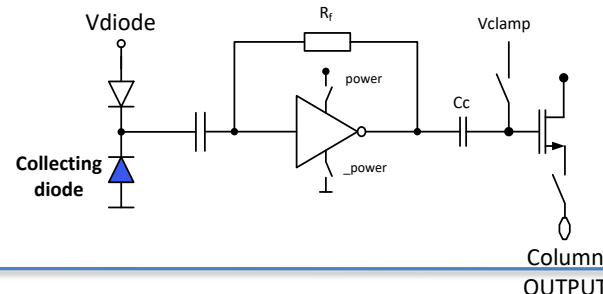


Mimosa 22SX



First 2D prototype specs

- Tower Jazz 180 nm CIS
- 128 x 256 pixels with 22μm pixel pitch
- Collecting diode AC coupled to ampli.
- Discriminator with 2 thresholds → energy windowing
- Binary outputs
- 16 mm² of active area



Application to charged beam

■ Dose Monitoring by counting



CYRCé Cyclotron at IPHC:

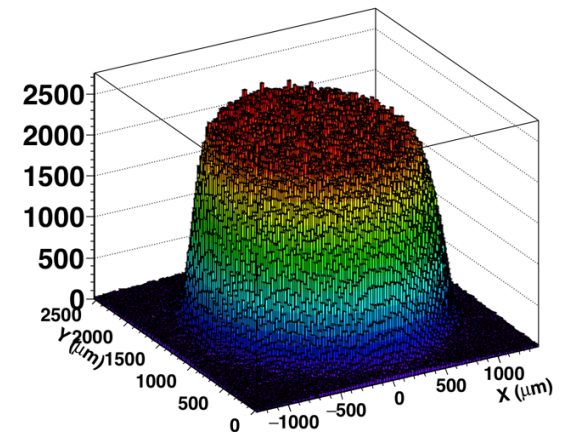
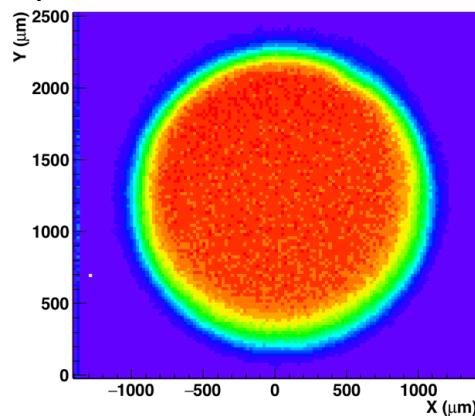
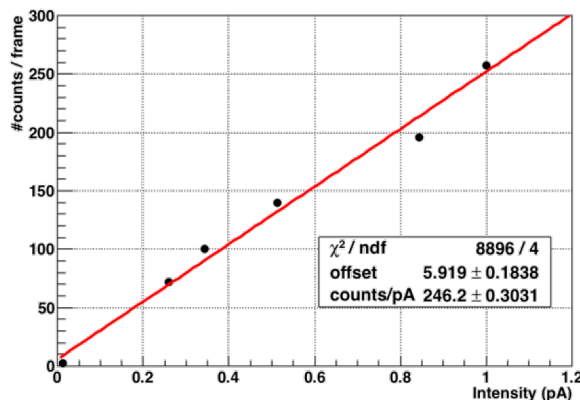
- 24 MeV protons
- Millimetre beam size for small animal proton therapy

Motivation:

Monitor dose for small beam size (problematic with current detector)

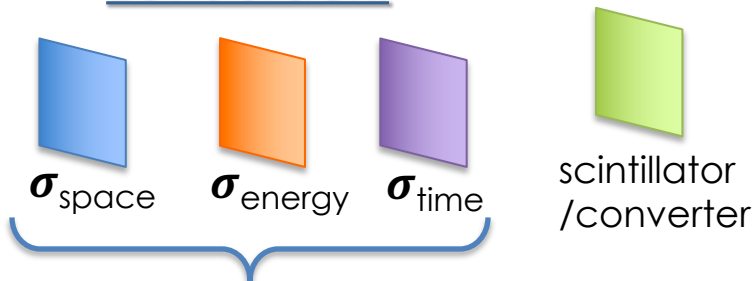
First tests with Mimosa 22SX

- Linear behaviour in the measured fluence range
- At least 1000 protons/pix/s possible

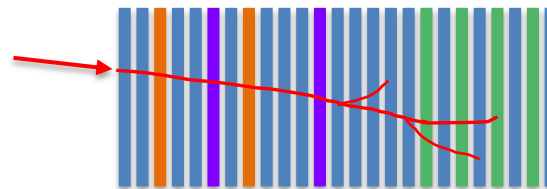


DREAM of electronic emulsion

Let's stack!



CMOS pixel flavours with sense layer ~ 100 % thickness

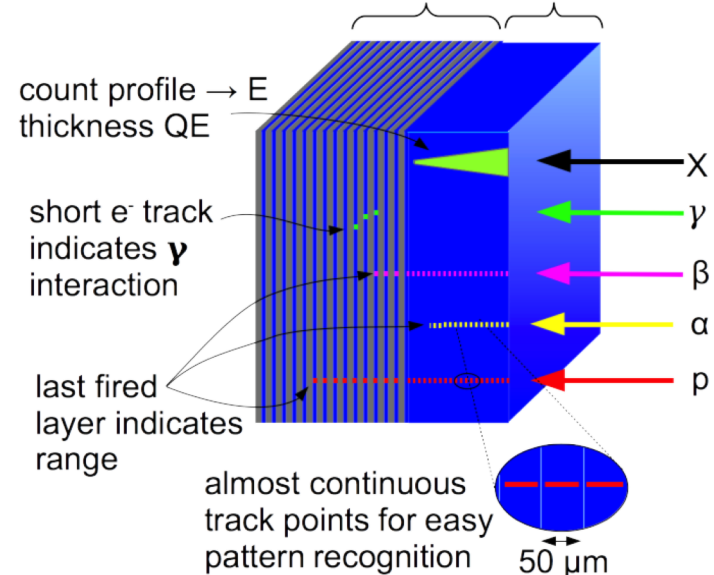


Fast electronic equivalent of a nuclear emulsion

- **8D measurements**
 - 3D position + 3D direction
 - 1D time
 - 1D energy (range / sampling)
- **Adjustable performances**
 - Stack re-shaping (sensor redesign)

“Calorimeter” Tracker

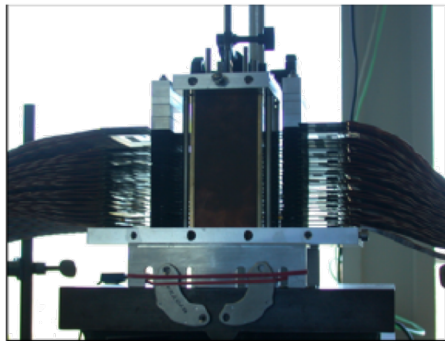
mixed scint. + Si sensors pure Si sensors



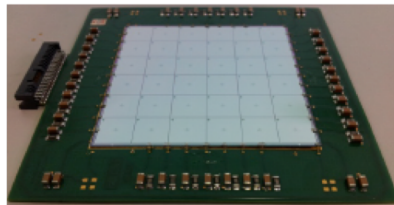
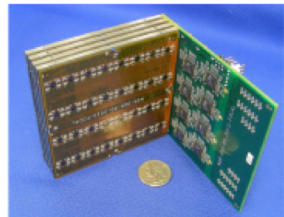
High-Granularity digital electromagnetic calorimetry

- Stack of (tungsten + MAPS) layers

24 layer pixel detector



Pad layer integration



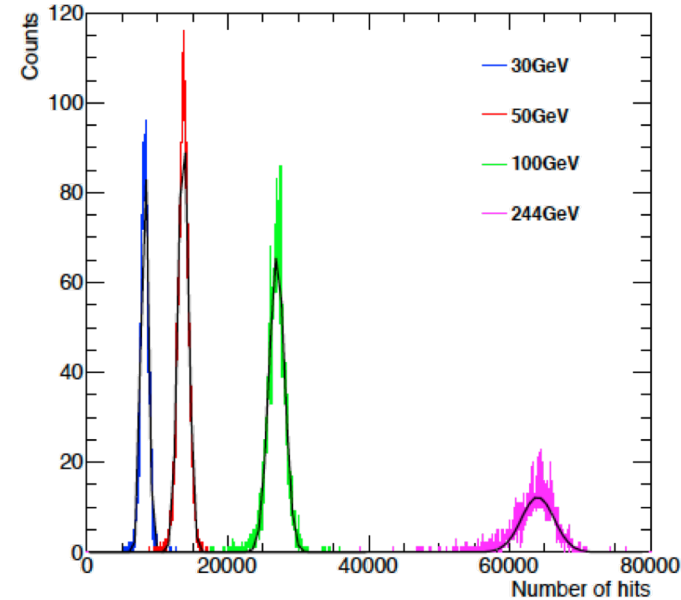
R&D Activities with Si-pad/W Calorimeter Prototypes (Japan/ORNL, India) not covered here

Several groups involved:

Full prototype with pixel detectors
 CMOS (MIMOSA) 39M pixels,
 30 μ m pitch
 use synergy with R&D for ALICE ITS
 upgrade
 Full prototype with pad readout

Performed systematic tests:

Test beam data from 2 to 250 GeV
 (DESY, PS, SPS)
 Cosmic muons



- response to electrons
 from SPS test beam

- calculated from per-event hit density
 distributions

Utrecht/Nikhef (Netherlands),
 Bergen (Norway),

Tsukuba, Nara, Hiroshima (Japan),
 ORNL (US)
 VECC Kolkata,
 BARC Mumbai (India)

- CMOS processes are evolving quickly
 - Followed with related integration technologies
 - Many labs and design companies are pushing various performances
 - Ex: spectrometry, electron multiplying CMOS, ...
 - „Full“ depletion of sensitive volume opened up:
 - Time resolution: today ~10 ns, tomorrow ~100 ps ?
 - Energy resolution: today ~5% for soft X-rays

- 2 depleted architectures emerging @ IPHC:
 1. Fast and/or time-resolved binary outputs (counting & tracking)
 2. Energy deposited measurement outputs

- Projects
 - Soft X-ray spectroscopy & counting (~1 cm² prototype in design)
 - Ionizing particle spectroscopy
(to be started with IPHC-DESiS group)
 - High energy particle identification from energy loss
(to be started with L.N.Frascati & IPHC-DRHIM)

BACKUPS

Energy resolution

After clustering → Seed pixel distribution

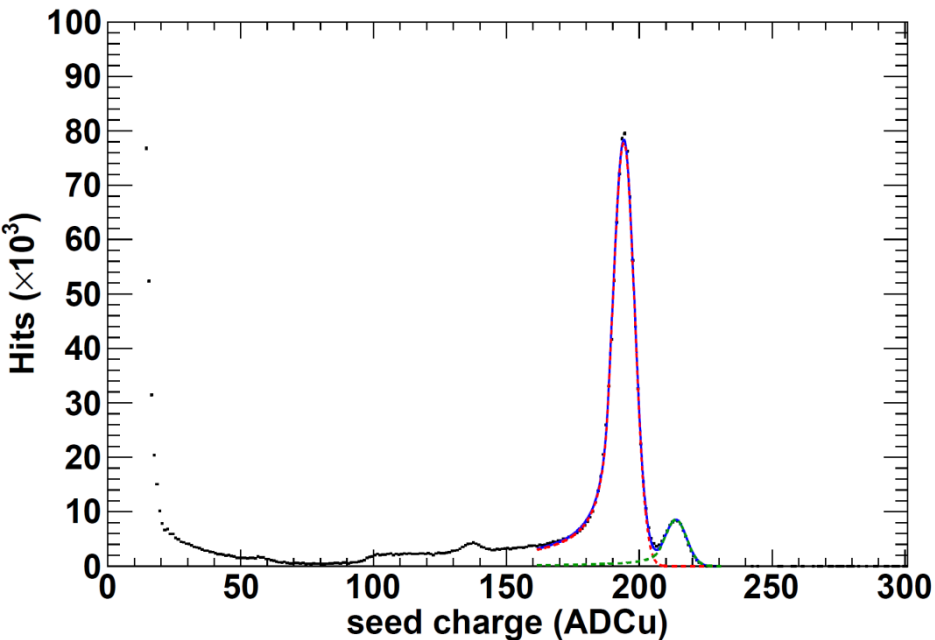
- Energy resolution dominated by pixel-gain & charge-collection fluctuations

○ HR-18

- ENC = 24 e⁻
- FWHM (5.9 keV) = 280 eV
- 75 % charges collected on the seed pixel

○ CZ

- ENC = 26 e⁻
- FWHM (5.9 keV) = 288 eV
- 68 % charges collected on the seed pixel

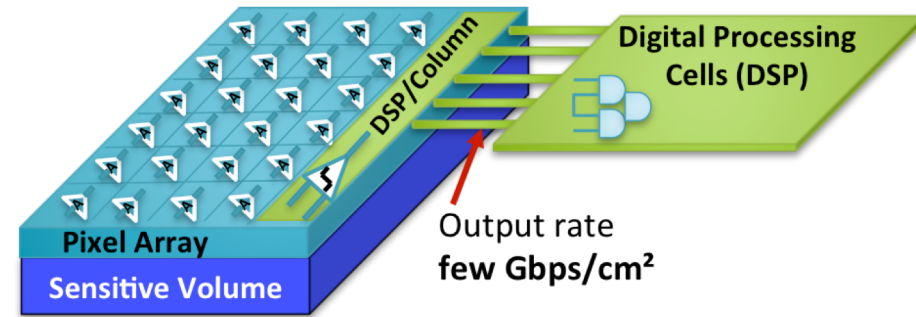


Pipper-2 measurements (presc. 2, T_{cool}=7 °C, V_{diode}=30V) ⁵⁵Fe irradiation – 400000 frames

Photon counting?

■ 2D architecture

- 1 sensor = **SYNAPS-2D**
- Rolling shutter with // columns analogue signal readout
 - 100-200 ns readout per row
 - About 512 rows
- Digitization (binary) at column end with energy window
- Dynamic range $1-2 \times 10^4$ photons/pixel/s



■ Mid/Long-term → 3D architecture

- 1 sensor + 1 DSP chip = **SYNAPS-3D**
- Local rolling-shutter within submatrix
 - 1 μ s readout per submatrix
 - ~ 10 photons (5 keV) dynamic per pixel
- Digitization + Memory in DSP
- Dynamic range $1-10^7$ photons/pixel/s

